

SN74GTLP2034

8-BIT LVTTTL-TO-GTLP ADJUSTABLE-EDGE-RATE REGISTERED TRANSCEIVER WITH SPLIT LVTTTL PORT AND FEEDBACK PATH

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description (continued)

GTLP is the Texas Instruments derivative of the Gunning Transceiver Logic (GTL) JEDEC standard JESD 8-3. The ac specification of the SN74GTLP2034 is given only at the preferred higher noise-margin GTLP, but the user has the flexibility of using this device at either GTL ($V_{TT} = 1.2\text{ V}$ and $V_{REF} = 0.8\text{ V}$) or GTLP ($V_{TT} = 1.5\text{ V}$ and $V_{REF} = 1\text{ V}$) signal levels. For information on using GTLP devices in FB+/BTL applications, refer to TI application reports, *Texas Instruments GTLP Frequently Asked Questions*, literature number SCEA019, and *GTLP in BTL Applications*, literature number SCEA017.

Normally, the B port operates at GTLP signal levels. The A-port and control inputs operate at LVTTTL logic levels, but are 5-V tolerant and can be directly driven by TTL or 5-V CMOS devices. V_{REF} is the B-port differential input reference voltage.

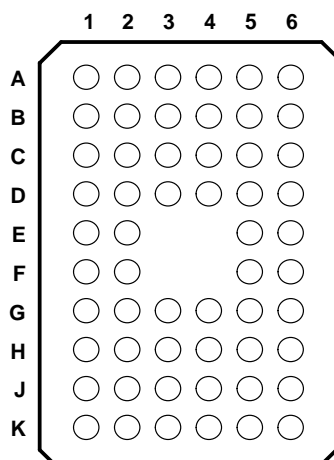
This device is fully specified for live-insertion applications using I_{off} , power-up 3-state, and BIAS V_{CC} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict. The BIAS V_{CC} circuitry precharges and preconditions the B-port input/output connections, preventing disturbance of active data on the backplane during card insertion or removal, and permits true live-insertion capability.

This GTLP device features TI-OPC circuitry, which actively limits overshoot caused by improperly terminated backplanes, unevenly distributed cards, or empty slots during low-to-high signal transitions. This improves signal integrity, which allows adequate noise margin to be maintained at higher frequencies.

High-drive GTLP backplane interface devices feature adjustable edge-rate control (ERC). Changing the ERC input voltage between low and high adjusts the B-port output rise and fall times. This allows the designer to optimize system data-transfer rate and signal integrity to the backplane load.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OEAB} should be tied to V_{CC} through a pullup resistor and OEAB and OEBA should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking/current-sourcing capability of the driver.

**GQL PACKAGE
(TOP VIEW)**



terminal assignments

	1	2	3	4	5	6
A	IMODE1	NC	NC	NC	NC	IMODE0
B	AO1	AI1	GND	GND	BIAS V_{CC}	B1
C	AO2	AI2	V_{CC}	ERC	OEAB	B2
D	AO3	AI3	GND	GND	\overline{OEAB}	B3
E	AO4	AI4			CLKAB/LEAB	B4
F	AO5	AI5			CLKBA/LEBA	B5
G	AO6	AI6	GND	GND	OEBA	B6
H	AO7	AI7	V_{CC}	V_{CC}	LOOPBACK	B7
J	AO8	AI8	GND	GND	V_{REF}	B8
K	OMODE0	NC	NC	NC	NC	OMODE1

NC = No internal connection



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ORDERING INFORMATION

T _A	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	TSSOP – DGG	Tape and reel	SN74GTLP2034DGGR	GTLP2034
	TVSOP – DGV	Tape and reel	SN74GTLP2034DGVR	GT2034
	VFBGA – GQL	Tape and reel	SN74GTLP2034GQLR	GR034

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

functional description

The SN74GTLP2034 is a high-drive (100 mA), 8-bit, three-wire registered transceiver containing D-type latches and D-type flip-flops for data-path operation in the transparent, latched, or flip-flop modes. Data transmission is true, with AI data going to the B port and B data going to AO. The split LVTTTL AI and AO provides a feedback path for control and diagnostics monitoring.

The logic element for data flow in each direction is configured by two mode (IMODE1 and IMODE0 for B to A, OMODE1 and OMODE0 for A to B) inputs as a buffer, D-type flip-flop, or D-type latch. When configured in the buffer mode, the input data appears at the output port. In the flip-flop mode, data is stored on the rising edge of the appropriate clock (CLKAB/LEAB or CLKBA/LEBA) input. In the latch mode, the clock inputs serve as active-high transparent latch enables.

Data flow in the B-to-A direction, regardless of the logic element selected, is further controlled by the LOOPBACK input. When LOOPBACK is low, B-port data is the B-to-A input. When LOOPBACK is high, the output of the selected A-to-B logic element is the B-to-A input.

The AO enable/disable control is provided by OEBA. When OEBA is low or when V_{CC} is less than 1.5 V, AO is in the high-impedance state. When OEBA is high, AO is active (high or low logic levels).

The B port is controlled by OEAB and \overline{OEAB} . If OEAB is low, \overline{OEAB} is high, or V_{CC} is less than 1.5 V, the B port is inactive. If OEAB is high and \overline{OEAB} is low, the B port is active.

The A-to-B and B-to-A logic elements are active, regardless of the state of their associated outputs. The logic elements can enter new data (in flip-flop and latch modes) or retain previously stored data while the associated outputs are in the high-impedance (AO) or inactive (B port) states.

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Function Tables

FUNCTION/MODE

INPUTS								OUTPUT	MODE
OEBA	OEAB	\overline{OEAB}	OMODE1	OMODE0	IMODE1	IMODE0	LOOPBACK		
L	L	X	X	X	X	X	X	Z	Isolation
L	X	H	X	X	X	X	X	Z	Isolation
X	H	L	L	L	X	X	X	AI to B	Buffer
X	H	L	L	H	X	X	X	AI to B	Flip-flop
X	H	L	H	X	X	X	X	AI to B	Latch
H	L	X	X	X	L	L	L	B to AO	Buffer
H	X	H	X	X	L	L	L	B to AO	Buffer
H	L	X	X	X	L	H	L	B to AO	Flip-flop
H	X	H	X	X	L	H	L	B to AO	Flip-flop
H	L	X	X	X	H	X	L	B to AO	Latch
H	X	H	X	X	H	X	L	B to AO	Latch
H	L	X	X	X	L	L	H	AI to AO	Buffer
H	X	H	X	X	L	L	H	AI to AO	Buffer
H	L	X	X	X	L	H	H	AI to AO	Flip-flop
H	X	H	X	X	L	H	H	AI to AO	Flip-flop
H	L	X	X	X	H	X	H	AI to AO	Latch
H	X	H	X	X	H	X	H	AI to AO	Latch
H	H	L	X	X	X	X	L	AI to B, B to AO	Transparent with feedback path

ENABLE/DISABLE

INPUTS			OUTPUTS	
OEBA	OEAB	\overline{OEAB}	AO	B
L	X	X	Z	
H	X	X	Active	
X	L	L		Z
X	L	H		Z
X	H	L		Active
X	H	H		Z

BUFFER

INPUT	OUTPUT
L	L
H	H

LATCH

INPUTS		OUTPUT
CLK/LE	DATA	
H	L	L
H	H	H
L	X	Q ₀



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Function Tables (Continued)

LOOPBACK

LOOPBACK	Q†
L	B port
H	Point P‡

† Q is the input to the B-to-A logic element.

‡ P is the output of the A-to-B logic element (see functional block diagram).

SELECT

INPUTS		SELECTED LOGIC ELEMENT
MODE1	MODE0	
L	L	Buffer
L	H	Flip-flop
H	X	Latch

FLIP-FLOP

INPUTS		OUTPUT
CLK/LE	DATA	
L	X	Q ₀
↑	L	L
↑	H	H

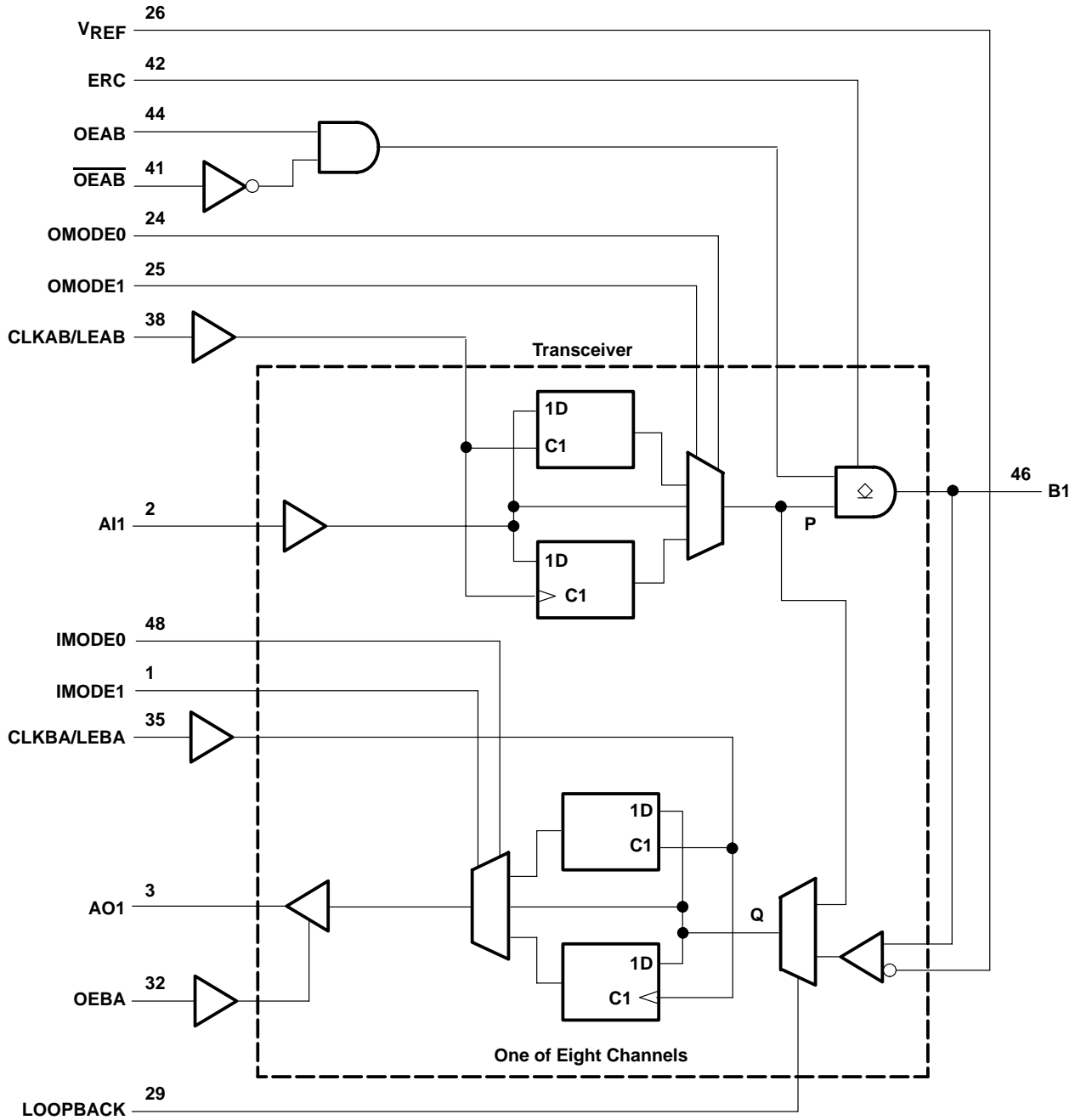
B-PORT EDGE-RATE CONTROL (ERC)

INPUT ERC	OUTPUT B-PORT EDGE RATE
LOGIC LEVEL	
H	Slow
L	Fast

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functional block diagram



Pin numbers shown are for the DGG and DGV packages.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} and BIAS V_{CC}	-0.5 V to 4.6 V
Input voltage range, V_I (see Note 1): AI port, ERC, and control inputs	-0.5 V to 7 V
B port and V_{REF}	-0.5 V to 4.6 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1): AO port	-0.5 V to 7 V
B port	-0.5 V to 4.6 V
Current into any output in the low state, I_O : AO port	48 mA
B port	200 mA
Current into any A-port output in the high state, I_O (see Note 2)	48 mA
Continuous current through each V_{CC} or GND	± 100 mA
Input clamp current, I_{IK} ($V_I < 0$)	-50 mA
Output clamp current, I_{OK} ($V_O < 0$)	-50 mA
Package thermal impedance, θ_{JA} (see Note 3): DGG package	70°C/W
DGV package	58°C/W
GQL package	42°C/W
Storage temperature range, T_{stg}	-65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 3. The package thermal impedance is calculated in accordance with JESD 51-7.



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recommended operating conditions (see Notes 4 through 7)

		MIN	NOM	MAX	UNIT	
V_{CC} , BIAS V_{CC}	Supply voltage	3.15	3.3	3.45	V	
V_{TT}	Termination voltage	GTLP	1.14	1.2	1.26	V
		GTL	1.35	1.5	1.65	
V_{REF}	Reference voltage	GTLP	0.74	0.8	0.87	V
		GTL	0.87	1	1.1	
V_I	Input voltage	B port	V_{TT}		V	
		Except B port and V_{REF}	V_{CC}	5.5		
V_{IH}	High-level input voltage	B port	$V_{REF}+0.05$		V	
		Except B port	2			
V_{IL}	Low-level input voltage	B port	$V_{REF}-0.05$		V	
		Except B port	0.8			
I_{IK}	Input clamp current			-18	mA	
I_{OH}	High-level output current	AO			-24	mA
I_{OL}	Low-level output current	AO			24	mA
		B port			100	
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10	ns/V	
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	20			$\mu s/V$	
T_A	Operating free-air temperature	-40		85	$^{\circ}C$	

- NOTES: 4. All unused control and B-port inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
5. Proper connection sequence for use of the B-port I/O precharge feature is GND and BIAS $V_{CC}=3.3$ V first, I/O second, and $V_{CC}=3.3$ V last, because the BIAS V_{CC} precharge circuitry is disabled when any V_{CC} pin is connected. The control and V_{REF} inputs can be connected anytime, but normally are connected during the I/O stage. If B-port precharge is not required, any connection sequence is acceptable but, generally, GND is connected first.
6. V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances if the dc recommended I_{OL} ratings are not exceeded.
7. V_{REF} can be adjusted to optimize noise margins, but normally is two-thirds V_{TT} . TI-OPC circuitry is enabled in the A-to-B direction and is activated when $V_{TT} > 0.7$ V above V_{REF} . If operated in the A-to-B direction, V_{REF} should be set to within 0.6 V of V_{TT} to minimize current drain.

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electrical characteristics over recommended operating free-air temperature range for GTLP (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}		$V_{CC} = 3.15\text{ V}$, $I_I = -18\text{ mA}$				-1.2	V
V_{OH}	AO	$V_{CC} = 3.15\text{ V to }3.45\text{ V}$, $I_{OH} = -100\text{ }\mu\text{A}$		$V_{CC}-0.2$			V
		$V_{CC} = 3.15\text{ V}$		2.4			
V_{OL}	AO	$V_{CC} = 3.15\text{ V to }3.45\text{ V}$, $I_{OL} = 100\text{ }\mu\text{A}$				0.2	V
		$V_{CC} = 3.15\text{ V}$		$I_{OL} = 12\text{ mA}$		0.4	
				$I_{OL} = 24\text{ mA}$		0.5	
	B port	$V_{CC} = 3.15\text{ V}$		$I_{OL} = 10\text{ mA}$		0.2	
				$I_{OL} = 64\text{ mA}$		0.4	
				$I_{OL} = 100\text{ mA}$		0.55	
I_I^\ddagger	AI and control inputs	$V_{CC} = 3.45\text{ V}$, $V_I = 0\text{ or }5.5\text{ V}$				± 10	μA
I_{OZ}^\ddagger	AO	$V_{CC} = 3.45\text{ V}$, $V_O = 0\text{ to }5.5\text{ V}$				± 10	μA
	B port	$V_{CC} = 3.45\text{ V}$, V_{REF} within 0.6 V of V_{TT} , $V_O = 0\text{ to }2.3\text{ V}$				± 10	
I_{CC}	AO or B port	$V_{CC} = 3.45\text{ V}$, $I_O = 0$, V_I (A-port or control input) = V_{CC} or GND, V_I (B port) = V_{TT} or GND		Outputs high		40	mA
				Outputs low		40	
				Outputs disabled		40	
ΔI_{CC}^\S		$V_{CC} = 3.45\text{ V}$, One AI or control input at $V_{CC} - 0.6\text{ V}$, Other AI or control inputs at V_{CC} or GND				1.5	mA
C_i	AI	$V_I = 3.15\text{ V or }0$			3.5	4.5	pF
	Control inputs				3.5	5.5	
C_o	AO	$V_O = 3.15\text{ V or }0$			5	6	pF
C_{io}	B port	$V_O = 1.5\text{ V or }0$			8.5	10	pF

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ For I/O ports, the parameter I_{OZ} includes the input leakage current.

§ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

hot-insertion specifications for A port over recommended operating free-air temperature range

PARAMETER	TEST CONDITIONS			MIN	MAX	UNIT
I_{off}	$V_{CC} = 0$,	V_I or $V_O = 0\text{ to }5.5\text{ V}$			10	μA
I_{OZPU}	$V_{CC} = 0\text{ to }1.5\text{ V}$,	$V_O = 0.5\text{ V to }3\text{ V}$,	$OEBA = V_{CC}$		± 30	μA
I_{OZPD}	$V_{CC} = 1.5\text{ V to }0$,	$V_O = 0.5\text{ V to }3\text{ V}$,	$OEBA = V_{CC}$		± 30	μA

live-insertion specifications for B port over recommended operating free-air temperature range

PARAMETER	TEST CONDITIONS			MIN	MAX	UNIT
I_{off}	$V_{CC} = 0$,	BIAS $V_{CC} = 0$,	V_I or $V_O = 0\text{ to }1.5\text{ V}$		10	μA
I_{OZPU}	$V_{CC} = 0\text{ to }1.5\text{ V}$,	BIAS $V_{CC} = 0$,	$V_O = 0.5\text{ V to }1.5\text{ V}$, $\overline{OEAB} = 0$ and $OEAB = V_{CC}$		± 30	μA
I_{OZPD}	$V_{CC} = 1.5\text{ V to }0$,	BIAS $V_{CC} = 0$,	$V_O = 0.5\text{ V to }1.5\text{ V}$, $\overline{OEAB} = 0$ and $OEAB = V_{CC}$	± 30	± 30	μA
I_{CC} (BIAS V_{CC})	$V_{CC} = 0\text{ to }3.15\text{ V}$	BIAS $V_{CC} = 3.15\text{ V to }3.45\text{ V}$, V_O (B port) = $0\text{ to }1.5\text{ V}$			5	mA
	$V_{CC} = 3.15\text{ V to }3.45\text{ V}$				10	μA
V_O	$V_{CC} = 0$,	BIAS $V_{CC} = 3.3\text{ V}$,	$I_O = 0$	0.95	1.05	V
I_O	$V_{CC} = 0$,	BIAS $V_{CC} = 3.15\text{ V to }3.45\text{ V}$,	V_O (B port) = 0.6 V	-1		μA



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timing requirements over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5\text{ V}$ and $V_{REF} = 1\text{ V}$ for GTLP (unless otherwise noted)

		MIN	MAX	UNIT
f_{clock}	Clock frequency		175	MHz
t_w	Pulse duration	CLKAB/LEAB or CLKBA/LEBA		ns
t_{su}	Setup time	A1 before CLKAB \uparrow		1.1
		A1 before CLKBA \uparrow		1.4
		B before CLKBA \uparrow		1.3
		A1 before LEAB \downarrow		1.3
		A1 before LEBA \downarrow		2.1
		B before LEBA \downarrow		2.2
t_h	Hold time	A1 after CLKAB \uparrow		0.3
		A1 after CLKBA \uparrow		0.2
		B after CLKBA \uparrow		0.2
		A1 after LEAB \downarrow		0.3
		A1 after LEBA \downarrow		0
		B after LEBA \downarrow		0



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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5\text{ V}$ and $V_{REF} = 1\text{ V}$ for GTLP (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE†	MIN	TYP‡	MAX	UNIT
f_{max}				175			MHz
t_{PLH}	AI (buffer)	B	Slow	3	7.1	7	ns
t_{PHL}				3			
t_{PLH}	AI (buffer)	B	Fast	2	5.6	5.7	ns
t_{PHL}				2			
t_{PLH}	B (buffer)	AO	–	1	5.4	4.8	ns
t_{PHL}				1			
t_{PLH}	LEAB (latch mode)	B	Slow	4.2	8.5	7.3	ns
t_{PHL}				3.2			
t_{PLH}	LEAB (latch mode)	B	Fast	3.2	7.1	6.3	ns
t_{PHL}				2.8			
t_{PLH}	LEAB (latch mode)	AO	–	2	6.6	5.8	ns
t_{PHL}				1.8			
t_{PLH}	LEBA (latch mode)	AO	–	1	5.3	4.5	ns
t_{PHL}				1			
t_{PLH}	OEAB	B	Slow	3.8	7.5	7	ns
t_{PHL}				3.1			
t_{PLH}	OEAB	B	Fast	2.5	6	6	ns
t_{PHL}				2.5			
t_{PLH}	\overline{OEAB}	B	Slow	3.5	7.5	7.2	ns
t_{PHL}				3			
t_{PLH}	\overline{OEAB}	B	Fast	2.5	6	6	ns
t_{PHL}				2.5			
t_{PZH}	OEBA	AO	–	1	4.7	3.4	ns
t_{PZL}				1			
t_{PHZ}	OEBA	AO	–	1	5.2	4.9	ns
t_{PLZ}				1			
t_{PLH}	CLKAB (flip-flop mode)	B	Slow	4.4	8.6	8	ns
t_{PHL}				3.6			
t_{PLH}	CLKAB (flip-flop mode)	B	Fast	3.2	7.1	6.8	ns
t_{PHL}				3.1			
t_{PLH}	CLKAB (flip-flop mode)	AO	–	2	6.9	6.4	ns
t_{PHL}				1.8			
t_{PLH}	CLKBA (flip-flop mode)	AO	–	1	5.6	4.9	ns
t_{PHL}				1			
t_{PLH}	OMODE	B	Slow	3.8	8.7	8.2	ns
t_{PHL}				3.2			
t_{PLH}	OMODE	B	Fast	2.7	7	7	ns
t_{PHL}				2.7			
t_{PLH}	IMODE	AO	–	1	5.6	4.6	ns
t_{PHL}				1			

† Slow (ERC = H) and Fast (ERC = L)

‡ All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.



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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5\text{ V}$ and $V_{REF} = 1\text{ V}$ for GTLP (see Figure 1) (continued)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE†	MIN	TYP‡	MAX	UNIT
t_{PLH}	LOOPBACK	AO	–	2.5		5.5	ns
t_{PHL}				2	4.7		
t_{PLH}	AI (loopback high)	AO	–	1		5.3	ns
t_{PHL}				1	4.9		
t_r	Rise time, B-port outputs (20% to 80%)		Slow	2.8		ns	
			Fast	1.5			
	Rise time, AO (10% to 90%)			3.5			
t_f	Fall time, B-port outputs (80% to 20%)		Slow	3		ns	
			Fast	1.8			
	Fall time, AO (90% to 10%)			1.5			

† Slow (ERC = H) and Fast (ERC = L)

‡ All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

skew characteristics over recommended ranges of supply voltage and operating free-air temperature (see Figure 1)§

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE†	MIN	TYP‡	MAX	UNIT
$t_{sk(LH)}^{\parallel}$	AI	B	Slow	0.5		1	ns
$t_{sk(HL)}^{\parallel}$				0.5	1		
$t_{sk(LH)}^{\parallel}$	AI	B	Fast	0.4		0.9	ns
$t_{sk(HL)}^{\parallel}$				0.4	0.9		
$t_{sk(LH)}^{\parallel}$	CLKAB/LEAB	B	Slow	0.5		1	ns
$t_{sk(HL)}^{\parallel}$				0.5	1		
$t_{sk(LH)}^{\parallel}$	CLKAB/LEAB	B	Fast	0.4		0.9	ns
$t_{sk(HL)}^{\parallel}$				0.4	0.9		
$t_{sk(t)}^{\parallel}$	AI	B	Slow	1.4		2	ns
			Fast	0.6	1.4		
	CLKAB/LEAB	B	Slow	1.8	2.5		
			Fast	0.9	1.8		

† Slow (ERC = L) and Fast (ERC = H)

‡ All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

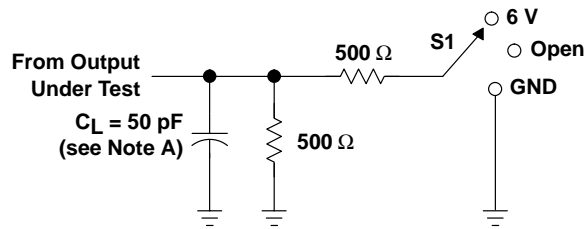
§ Actual skew values between the GTLP outputs could vary on the backplane due to the loading and impedance seen by the device.

¶ $t_{sk(LH)}/t_{sk(HL)}$ and $t_{sk(t)}$ – Output-to-output skew is defined as the absolute value of the difference between the actual propagation delay for all outputs with the same packaged device. The specifications are given for specific worst-case V_{CC} and temperature and apply to any outputs switching in the same direction either high to low [$t_{sk(HL)}$] or low to high [$t_{sk(LH)}$] or in opposite directions, both low to high and high to low [$t_{sk(t)}$].

SN74GTLP2034
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WITH SPLIT LVTTTL PORT AND FEEDBACK PATH

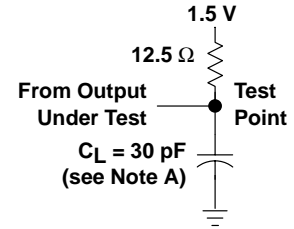
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PARAMETER MEASUREMENT INFORMATION

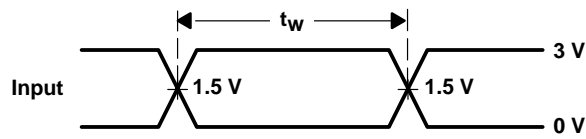


LOAD CIRCUIT FOR A OUTPUTS

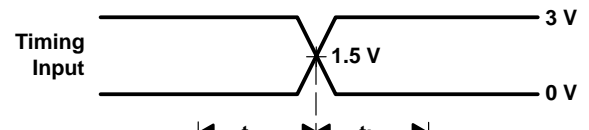
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	6 V
t _{PHZ} /t _{PZH}	GND



LOAD CIRCUIT FOR B OUTPUTS



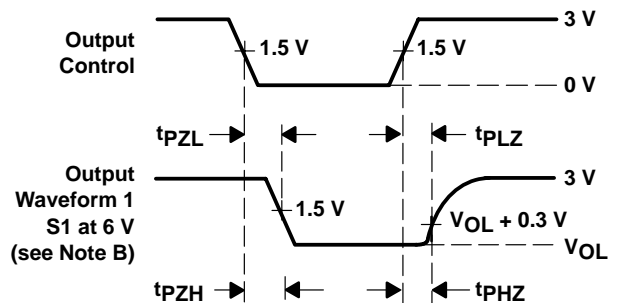
**VOLTAGE WAVEFORMS
PULSE DURATION**



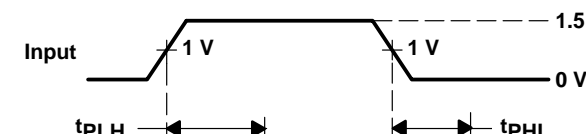
**VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES**
 (VM = 1.5 V for A port and 1 V for B port)
 (VOH = 3 V for A port and 1.5 V for B port)



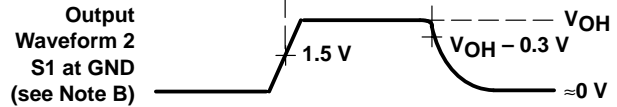
**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
(A to B port)**



**VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
(AO)**



**VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
(B port to AO)**



- NOTES: A. CL includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR = 10 MHz, ZO = 50 Ω, tr ≈ 2 ns, tf ≈ 2 ns.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

DISTRIBUTED-LOAD BACKPLANE SWITCHING CHARACTERISTICS

The preceding switching characteristics table shows the switching characteristics of the device into a lumped load (Figure 1). However, the designer’s backplane application is probably a distributed load. The physical representation is shown in Figure 2. This backplane, or distributed load, can be closely approximated to a resistor inductance capacitance (RLC) circuit, as shown in Figure 3. This device has been designed for optimum performance in this RLC circuit. The following switching characteristics table shows the switching characteristics of the device into the RLC load, to help the designer to better understand the performance of the GTLP device in this typical backplane. See www.ti.com/sc/gtlp for more information.

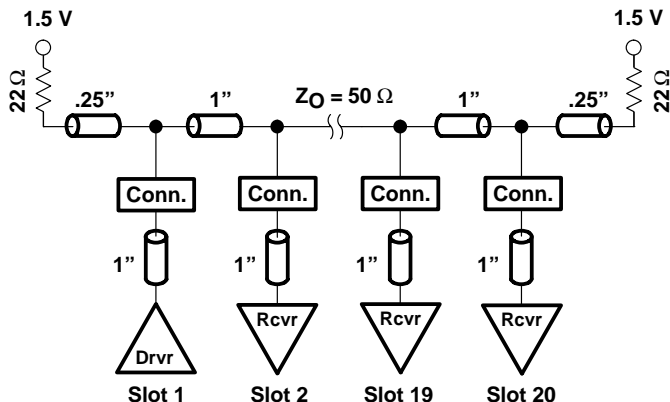


Figure 2. High-Drive Test Backplane

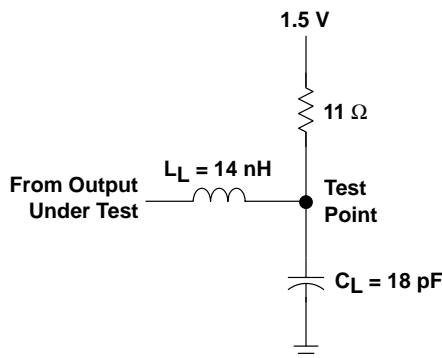


Figure 3. High-Drive RLC Network

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switching characteristics over recommended operating conditions for the bus transceiver function (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	EDGE RATE†	TYP‡	UNIT
t _{PLH}	AI (buffer)	B	Slow	5.7	ns
t _{PHL}				5.2	
t _{PLH}	AI (buffer)	B	Fast	3.7	ns
t _{PHL}				4.1	
t _{PLH}	LEAB (latch mode)	B	Slow	5.9	ns
t _{PHL}				5.7	
t _{PLH}	LEAB (latch mode)	B	Fast	4.8	ns
t _{PHL}				4.8	
t _{PLH}	CLKAB (flip-flop mode)	B	Slow	5.7	ns
t _{PHL}				6.4	
t _{PLH}	CLKAB (flip-flop mode)	B	Fast	4.7	ns
t _{PHL}				5.2	
t _{PLH}	OMODE	B	Slow	5.4	ns
t _{PHL}				6	
t _{PLH}	OMODE	B	Fast	4.5	ns
t _{PHL}				4.9	
t _r	Rise time, B-port outputs (20% to 80%)		Slow	2	ns
			Fast	1.1	
t _f	Fall time, B-port outputs (80% to 20%)		Slow	3.3	ns
			Fast	2.3	

† Slow (ERC = H) and Fast (ERC = L)

‡ All typical values are at V_{CC} = 3.3 V, T_A = 25°C. All values are derived from TI-SPICE models.

DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

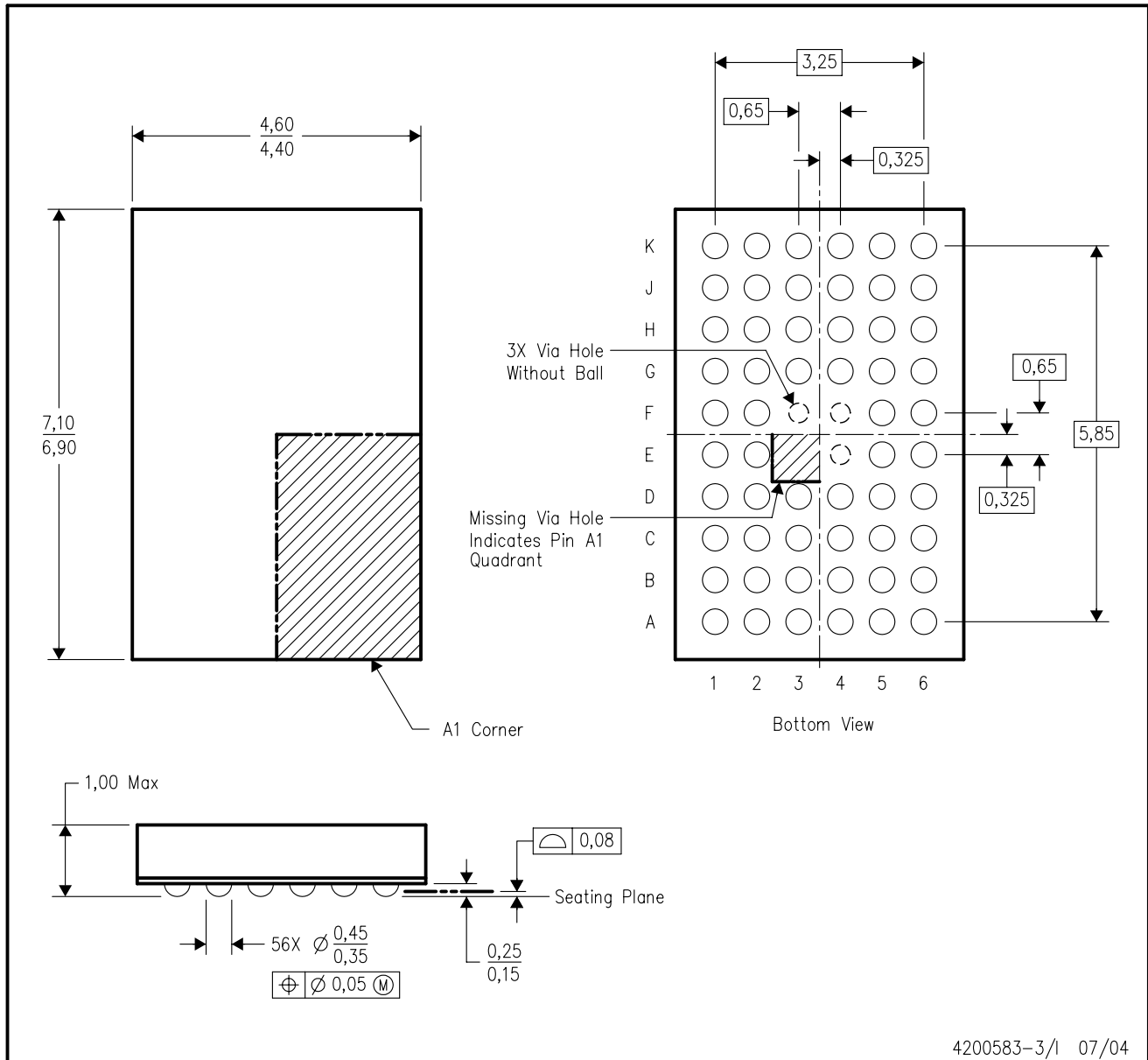
24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY

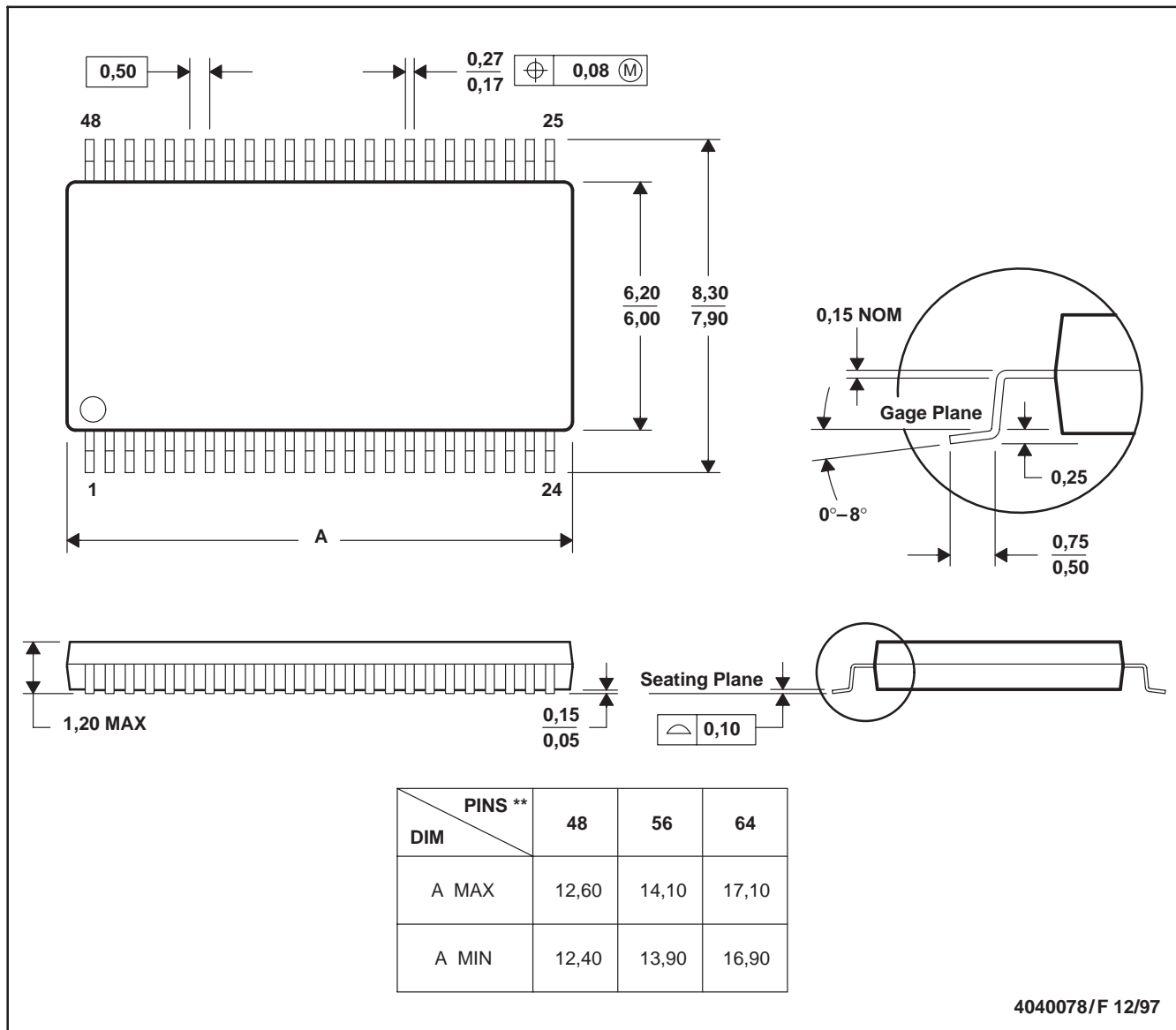


- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MO-225 variation BA.
 - D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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Mailing Address: Texas Instruments
Post Office Box 655303 Dallas, Texas 75265